



GENERAL DESCRIPTION

The model FT 620B VHF SSB transceiver is specifically designed to provide a high performance, compact transceiver for amateur VHF SSB, AM and CW service, base or mobile.

The FT 620B is completely solid state with provision for VFO operation covering entire 6 meter amateur bands in eight segments. In addition to the VFO operation, 4 crystal controlled channels are provided. Advanced design features include noise blanker, squelch circuit, CW break in and AFP (automatic final protection) circuit to prevent damage to the transistors in case of high antenna VSWR.

The FT 620B is self-contained, requiring only an antenna and power source for home or mobile operation. The FT 620B may be operated from 100/110/117/200/220 or 234 volts AC (normally supplied wired for 117 volts), or 13.5 volts DC. Two power cables are supplied with the transceiver. Selection of AC or DC power source is automatically made when the proper power cable is connected to the transceiver. The FT 620B VHF transceiver is supplied complete with cables, connectors, microphone and accessories, as shown below.



Figure 1

- (1) Dynamic push-to-talk microphone YM-86 with retractable coiled cord.
- (2) Phone plug for headphone or key.
- (3) Miniature phone plug for external speaker.
- (4) 7-pin male connector for accessory receptacle.
- (5) AC power cable.
- (6) DC power cable.
- (7) Spare fuses, 2A for AC, 3A for DC operation.
- (8) Alignment tool.

SPECIFICATIONS

GENERAL

Frequency Range	50.0 - 50.5 MHz, 50.5 - 51.0 MHz, 51.0 - 51.5 MHz, 51.5 - 52.0 MHz, 52.0 - 52.5 MHz, 52.5 - 53.0 MHz, 53.0 - 53.5 MHz, 53.5 - 54.0 MHz. (52.0 - 54.0 MHz crystals are options.)
Emission	SSB (USB or LSB selectable), AM, and CW.
Power Requirement	 AC 100/110/117/200/220/234 volts. 50/60 Hz. DC 12.5 - 14 volts, negative ground. (13.5 volts DC nominal)
Power Consumption	AC Receive 16VA. Transmit 60VA. DC Receive 0.3A. Transmit 2A.
Speaker	Internal dynamic speaker. 10 cm diameter with provision for connecting external 4 ohm dynamic speaker.
Microphone	Dynamic push-to-talk microphone with retractable coiled cord, 10 kilo ohm impedance.
Size	280(W), 125(H), 295(D) m/m.
Weight	8 kg. approx.

TRANSMITTER

Final Input	SSB, C	CW 20	watts DC.
	AM	8	watts DC.

Carrier Suppression 40 dB or better.

Unwanted Sideband Suppression

... 40 dB or better.

Spurious Radiation	60 dB below carrier.
Frequency Response	300 - 2700 Hz within ± 3 dB.
Antenna Impedance	50 ohms unbalanced.

RECEIVER

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Sensitivity	SSB	Less than 0.5 uV input for 10 dB STN/N.
	AM	Less than 1 uV input for 10 dB STN/N.
Selectivity	SSB	2.5 kHz at -6 dB. 4.1 kHz at -60 dB.
	AM	6 kHz at -6 dB. 10 kHz at -60 dB.
		(with optional AM filter)
Image Rejection	60 dI	3 or better.
Audio Output	2.0 v	vatts at 10% distortion

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SEMICONDUCTORS COMPLEMENT

TRANSISTOR

2SC372Y	20	2SC1216	1
2SC373	1	2SC1306	1
2SC710D	3	2SC1307	1
2SC735Y	1	2N 3055	1
2SC784R	6	2SD313E	2
2SC828Q	2 .		

FET

2SK19	8
35K40M	3

INTEGRATED CIRCUIT

AN214	1	TA7045M	1
SN7490N	1		

SCR

CW01B 1

DIODE

1S2236	· 1	DS130ND	1
1S188FM	9	KBL02	1
1S1007	7	V06B	4
1S1209	2	WZ061	1
lS1555	6	WZ090	2
15330	1	WZ110	2

INSTALLATION

GENERAL

The transceiver is designed to provide a complete single unit installation for fixed, portable, or mobile operation. Two prewired plugs are supplied with the unit for AC or DC power source. This system provides the flexibility required for various installation and allows rapid change from base to mobile operation.

BASE STATION INSTALLATION

The transceiver is designed for use in many countries in the world using supply voltage that may differ from the operator's local supply voltage. Therefore, prior to connecting the AC cable to the power outlet, be sure that the voltage marked on the rear of the transceiver agrees with the local AC supply voltage.

CAUTION

PERMANENT DAMAGE WILL RESULT IF IMPROPER AC SUPPLY VOLTAGE IS APPLIED TO THE TRANSCEIVER.

The transceiver should be connected to a good ground. The ground lead should be as short as possible and connected to the terminal marked GND on the rear panel.

MOBILE INSTALLATION

The transceiver will operate satisfactorily from any 12 volt negative ground battery source by connecting the DC power cable to the rear panel receptacle.

For under-dash mounting, a mounting bracket is available from your local dealer. A location should be selected celar of heater ducts. No special mounting precautions be observed if adequate ventilation space is available. Never stack other units above or below the cabinet since the accumulated heat from both units could cause permanent damage. The transceiver requires an average of 2 amps on transmit. The fuse in the DC power cable should be rated at 3 amps. The power cable may be plugged directly into the vehicle's cigar lighter receptacle for casual operation if desired. For permanent installation, the lighter plug may be removed and the leads routed directly to the battery (RED positive, BLACK negative or ground), or to the nearest termination of the battery, i.e. fuse block, etc. If it is necessary to extend the power cable, use #16 AWG insulated copper wire and do not make the leads any longer than required, otherwise excessive voltage drop may occur.

CAUTION

BEFORE CONNECTING THE POWER CABLE TO THE TRANSCEIVER, CHECK THE BATTERY VOLTAGE WITH THE ENGINE RUNNING AND THE BATTERY CHARGING. IF THE VOLTAGE EXCEEDS 14.5 VOLTS DC, THE REGULATOR SHOULD BE READJUSTED SO THAT THE HIGHEST CHARGING VOLTAGE DOES NOT EXCEED 14.5 VOLTS. ALSO BE SURE TO OBSERVE PROPER POLARITY WHEN MAKING BATTERY CONNECTIONS. REVERSED CONNECTION COULD DAMAGE THE TRANSCEIVER PERMANENTLY.

ANTENNA

CAUTION

NEVER TRANSMIT WITHOUT HAVING PROPER ANTENNA OR DUMMY LOAD CONNECTED TO THE TRANSCEIVER.

The transceiver is designed for use with resonant antenna having an impedance of 50 ohm resistive load. The antenna is usually the most critical part of a station installation. Results both in receiving and transmitting will depend on how well the antenna is installed and adjusted. Any of common antenna systems, such as dipole, cubical quad, Yagi beam, designed for use on the 6 meter amateur bands may be used with the transceiver, provided the input impedance of the antenna system is 50 ohms.

The antenna should always be as high and in the clear as possible. Also, in mobile installation, it is advisable to locate the antenna as far from the engine as practical to minimize ignition noise pick up. In all installations, ensure that the antenna VSWR is less than 1.5 : 1. For mobile installation, the most popular antenna is vertical type, either a quarter wave length whip with unity gain, or a 5/8 wave length whip affording approximately 3.5 dB gain.

To minimize loss in the antenna system, use the shortest possible length of coaxial cable, avoiding any sharp angles or kinks. Use type RG-8U cable if the transmission line length exceeds 25 feet. The RG-58U cable is suitable for shorter length.

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The transceiver is specifically designed for ease of operation and versatility. All controls have been preset at the factory. Be sure you thoroughly understand the function of each control before operating the transceiver.



Figure 2. Front Panel

- (1) POWER
- (2) MODE SELECTOR
- (3) BAND
- (4) CLARIFIER

- Main switch. When pressed first, turns the transceiver ON for both AC and DC, and when pressed second, turns the transceiver OFF.
- Selects the mode of operation; AM, CW, USB or LSB.
- Selects the desired band in 50 54 MHz split into eight 500 kHz segments.
- Provides a means of turning the receiver frequency a few kHz to either side of the transmitting frequency. Thus it is possible to set the pitch of the voice you are receiving to the most readable point without affecting your transmitting

frequency. The receiver frequency may be locked to transmitting frequency at OFF position.

- (5) CALIB Is used to calibrate the dial readout with 100 kHz marker signal.
- (6) TUNING KNOB

 The tuning knob (VFO) directly below the main dial window in combination with the band switch. Determines actual operating frequency.
- (7) SQUELCH
 Adjusts the receiver squelch threshold sensitivity. At fully counter-clockwise position, the internal 1 MHz marker generator is on for the dial calibration.
- (8) AF GAIN
 Adjusts the audio output level at the speaker and phone jack. Clockwise rotation increases the audio output. When pulled, the noise blanker works.
- MIC GAIN

 Adjusts the audio level from the microphone amplifier stages. Clockwise rotation increases the microphone gain.
- (10) PRESELECTOR Tunes the signal circuit for both transmit and receive.
- (11) AM CARRIER Controls carrier level for AM mode operation.
- (12) VFO SELECT Selects VFO or four fixed crystal oscillator positions. Normal operation by VFO requires that VFO push button is depressed.
- (13) PHONES Headphone may be inserted in this jack. The internal speaker is disconnected when the plug is installed.

(14) MIC - Microphone jack.

- (15) METER Indicates signal strength and a relative power output in transmit.
- (16) CLAR With the clarifier ON, this indicator lights up.
- (17) FIX Lights up when the crystal controlled channel is selected instead of VFO control.



Figure 3. Rear Panel

(1)	POWER	-	Power receptacle. Both AC and DC cables are supplied.
(2)	ACC	-	Accessory socket. Provides access to transceiver operating voltages and relay contacts.
(3)	FUSE	-	Fuse holder requires 1 amp for AC operation.
(4)	KEY	-	Key jack for code operation.
(5)	EXT SP	-	Audio output is provided at this jack for an external speaker. Output impedance is 4 ohms.
(6)	GND	-	Ground connection.
(7)	ANT	-	Coaxial connector for antenna.
(8)	TONE	-	Sidetone output level adjustment for CW operation.

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INITIAL CHECK

Before connecting the transceiver to a power source, carefully examine the unit for any visible damage. Ensure that the voltage specification marked on the rear panel matches the supply voltage.

FREQUENCY SELECTION

The main tuning dial has two colored scales, white and green, for proper frequency readout with the setting of BAND switch.

The operator reads the white scale for the BAND switch setting of 50.0, 51.0, 52.0 and 53.0 MHz, and the green scale for 50.5, 51.5, 52.5 and 53.5 MHz.

The sub-dial in window is marked in 1 kHz increments and provides accurate setting of the operating frequency. The setting shown in the example, Fig. 4, would then be 51.1325 MHz when the BAND switch is set to 51.0 MHz. When the BAND switch is set to 51.5 MHz, then the above setting would be 51.6325 MHz.



Figure 4

1 KHz/10 KHz Window

RECEIVER CALIBRATION

(1) Preset the controls and switches as follows:

POWER	:	OFF
MODE	:	Desired mode
BAND	:	Desired band
CLARIFIER	:	OFF
SQUELCH	:	Position 1
AF GAIN	:	Position 5
SELECT SW	:	VFO
PRESELECTOR	:	Operating frequency position
MAIN TUNING KNOB	:	100 kHz point

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- (2) Press the POWER switch. Meter and dial lamps will light and noise or signal may be heard from the speaker.
- (3) To calibrate, set the TUNING control to the 100 kHz point in the dial nearest the desired operating frequency. Rotate the SQUELCH control fully counter-clockwise position to switch the 1 MHz calibrator on. Set the sub-dial to zero position. Push down the CALIB knob under the main tuning knob and zero beat with the main tuning knob against the 100 kHz marker signal. Depress the CALIB knob.

NOTE : Marker unit is an option and not supplied with the transceiver.



Figure 5

RECEIVE

Connect an antenna to the ANT connector on the rear panel. Tune the transceiver to a desired signal. Depress the MODE switch to the desired mode of operation. Tune the PRESELECTOR for maximum S-meter reading. Adjust the AF GAIN for audible level. When the AUDIO GAIN control is pulled, the noise blanker is placed in the circuit for elimination of noise pulses caused by auto ignition. The CLARIFIER may be used to set the pitch of the voice you are receiving to the most readable point without affecting your transmitting frequency. Its use is particularly valuable in "net" operation when several participants may be transmitting slightly off frequency. The CLARIFIER control may be switched off and the receiver frequency locked to the transmitting frequency by setting the CLARIFIER control to the OFF position. Normally, you will want to keep the CLARIFIER in the OFF position until the initial contact is made. The CLARIFIER control may then be used to zero-in and correct any drift on the received signal.

TRANSMIT

CAUTION

NEVER TRANSMIT WITHOUT HAVING PROPER ANTENNA OR DUMMY LOAD CONNECTED TO THE TRANSCEIVER.

1. SSB Operation

- (1) Connect a microphone to the MIC jack on the front panel.
- (2) Press a desired mode switch, LSB or USB.
- (3) Set the MIC GAIN control to 12 o'clock position.
- (4) Press the push-to-talk switch on the microphone and speak normally into the microphone.
- (5) The meter shows the modulated output power and meter deflection corresponds to the strength of the audio speech.
- (6) When the push-to-talk switch is released, the transceiver reverts to the receive mode.

CAUTI.ON

EXCESSIVE MIC GAIN WILL CAUSE DISTORTION ON TRANS-MITTED SIGNAL.

- 2. AM Operation
 - (1) Press the AM mode switch.
 - (2) Set the MIC GAIN control to zero position.
 - (3) Press the push-to-talk switch on the microphone.
 - (4) Adjust the AM CARRIER control on the front panel until the meter indicates 1/5 of the maximum meter deflection available for CW transmission.

- (5) Advance the MIC GAIN control until the meter indicates very slight movement with voice peaks while speaking normally into the microphone.
- 3. CW Operation
 - (1) Connect a key to the KEY jack on the rear panel.
 - (2) Press the CW mode switch. The transceiver is now ready for code transmission. With key down, the meter will indicate 8.
 - (3) With key up, the receiver will recover automatically. The relay hold time may be adjusted by VR902 on the TONE unit board under the chassis.



Figure 6. Key and Microphone Connections

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The block diagram and the circuit description will provide you with a better understanding of this transceiver.



FT 620B BLOCK DIAGRAM

RECEIVER SIGNAL PASS

Signal from the antenna is fed to the first gate of Q401, 3SK40M field effect transistor through low pass filter, antenna relay and IF trap. The AGC (automatic gain control) voltage is applied to the second gate of Q401. Amplified signal output from the Q401 is then coupled to the gate of Q402, 2SC784R, first mixer where the incoming signal is mixed with a signal from the first local oscillator. The signal is converted to 14 - 14.5 MHz first IF signal. The first IF signal is applied to the first gate of Q403, 3SK40M, the second mixer. The VFO signal is applied to the second gate of Q403 where the first IF signal is converted to 9 MHz second IF signal. The second IF signal is amplified by Q201 and Q202, 2SC784R, and fed to the crystal filter XF-90A through noise blanker gate diode D204, 1S1007. The 6 kHz AM filter, XF-90B, is an optional feature available at additional cost. Diode switch is used to select the filter. Without the optional AM filter, all signals are passed through SSB filter.

The signal passing the crystal filter is then amplified by Q207, 2SC784R, and Q206, TA7045M. For SSB and CW, the amplified signal is coupled to the demodulator which is used as modulator in transmit. For AM, the signal is applied to D211, 1S188FM, detector diode. The carrier oscillator oscillates either 8998.5 kHz for LSB or 9001.5 kHz for USB depending upon whether Q305, 2SC710D, or Q304, 2SC710D, is selected by the mode switch. The mode switch disconnects the emitter circuit of either transistor when not in use.

The output from the oscillator is fed to the balanced demodulator. These crystal frequencies are matched to the bandpass characteristics of the crystal filter. The 9001.5 kHz output is also used as BFO voltage for the CW reception.

Demodulated signal is fed to the base Q214, 2SC372Y, audio voltage amplifier through the mode switch and audio gain control potentiometer. The amplified signal is then fed to Q215, AN214, audio power amplifier. Q215 delivers 3.5 watt output to the speaker.

TRANSMITTER SIGNAL PASS

Speech from the microphone is fed to the first mic amplifier Q301, 2SC372Y. Input impedance of the microphone amplifier is 50 kilo ohms. The signal controlled in amplitude by the MIC GAIN control is amplified by the second mic amplifier Q302, 2SC372Y, and applied to the emitter flower Q303, 2SC372Y, to be delivered to the modulator.

For AM operation, the signal is fed directly to the modulator Q217, 2SC372Y. For SSB operation, the signal is fed to the balanced modulator through relay contacts. For CW operation, the output of the microphone amplifier is grounded.

The carrier oscillator oscillates either 8998.5 kHz for LSB or 9001.5 kHz for USB depending upon whether Q304, 2SC710D, or Q305, 2SC710D, is selected by the mode switch. The output from the oscillator is fed to the balanced modulator. These crystal frequencies are matched to the characteristics of the crystal filter to place the carrier frequency approximately 25 dB down on the skirt of the filter response. The modulated double sideband signal is amplified by the first IF amplifier Q205, 2SK19GR, and then fed to the crystal filter, XF-202, where unwanted sideband is filtered. The single sideband signal is then amplified by the second IF amplifier Q206, 2SK19GR.

For CW and AM, a separate oscillator Q216, 2SC710D, oscillates 9000.7 kHz carrier signal. This signal is fed to the AM modulator Q217, 2SC372Y, which works as a buffer amplifier for CW operation.

The output signal (9 MHz) from Q206 or Q217 is fed to the first gate of the transmitter first mixer Q404, 3SK40M, where the signal is converted into 14 - 14.5 MHz IF signal with the VFO signal applied to the second gate of Q404.

The 14 - 14.5 MHz IF signal is then fed to the transmitter second mixer Q405, 2SK19Y, and converted into the transmitting signal. This transmitting signal is applied to the four stage amplifier chain Q406, 2SC784R, Q407, 2SC1216, Q501, 2SC1306, and Q502, 2SC1307. The amplified signal is fed to the antenna connector through antenna change over relay and a low pass filter.



Figure 6

COMMON CIRCUIT

As described in the previous pages, the carrier oscillator, modulator and filter are used in common for transmitting and receiving. The following circuits are also used in common for transmitter and receiver.

1. Heterodyne Crystal Oscillator Circuit

Crystal controlled oscillator Q701, 2SC373, oscillates the heterodyne local signal for receiver first mixer and transmitter second mixer. One of eight crystals is selected by the BAND switch to cover 500 kHz segment. The output from the oscillator is fed to the source of Q402 and Q405 through an output coil L703.

2. VFO and FIX Oscillator Circuit

The VFO signal is generated by Q601, 2SC372Y, and fed to the buffers Q602, 2SC372Y, Q603, 2SK19GR, and Q802, 2SC372Y, which provide isolation and amplification of the VFO signal. The VFO oscillation frequency is 5,000 - 5,500 kHz and covers tunable IF range of 500 kHz. Varactor diode D601, 1S2236, is connected into the circuit by the clarifier switch, and this diode is used to shift the VFO frequency when the operating mode is changed.

In addition to the normal VFO operation, one of four crystals may be selected for crystal controlled operation by the CH1 - CH4 push button switch. For oscillator, Q801, 2SC372Y, is used and its output is fed to a buffer amplifier Q802, 2SC372Y. The crystal frequency may be corrected by series connected trimmer capacitors TC801 - TC804.

The output from VFO or crystal oscillator is amplified by buffer amplifier Q802, 2SC372Y, and fed through the band pass filter to the second gate of Q403 and Q404.

POWER SUPPLY

The power supply is designed to operate from either 100/110/117/200/220/234 volts AC or 12 volts DC (negative ground). Inserting the appropirate power plug into the rear panel receptacle makes necessary connections to operate the supply in either AC or DC.

When the AC cord is inserted, AC voltage is applied to pins 1 and 2, and fed to the power transformer through fuse and power switch. The secondary output of the power transformer is rectified by KBL-02 rectifier, and fed to the voltage regulator Q1, 2N3055, to obtain regulated 13.5 volts DC supply.

A part of the 13.5 volt supply is fed to other voltage regulator which consists of Q102, 2SD313E, and Q104, 2SC372Y, to obtain an extremely stable 9 volts DC supply. For DC operation, DC voltage is applied to pin 3 and 4 of the receptacle. This voltage is supplied to the transceiver through power switch. The regulator circuit by Q102 and Q104 is used for the regulated 9 volt supply.

AUXILIARY CIRCUIT

In addition to the basic circuit described above, a number of auxiliary circuits are adopted to optimize the performance of this transceiver.

1. Noise Blanker

Output from the receiver first IF Q201 is amplified by the noise amplifier Q218 and Q219, 2SK19GR. The signal amplified by Q218 and Q219 is rectified by D201, 1S1555, and biases D202, 1S1555. D202 conducts with the noise pulse and the negative output voltage from the diode is applied to the gate of Q203, 2SK19GR, in order to turn off Q203. Then the noise blanker driver Q204, 2SC372Y, conducts to switch a noise blanker diode D204, 1S1555, which disconnects the input circuit of the filter. The switching level is adjusted by the noise blanker threshold control VR201. At the most effective blanking position, there may be slight distortion on the received signal due to mixing at the switching diode. This effect can be reduced by readjusting the threshold control slightly.

2. AGC (Automatic Gain Control) Circuit

A part of output from receiver IF amplifier Q208 is rectified by voltage doubler D212 and D213, 1S1007. This DC voltage is amplified by AGC amplifier Q209, 2SC828Q, and applied to the RF amplifier Q401, IF amplifier Q207 and Q208 to reduce the gain automatically when a strong signal is received. This AGC voltage is amplified by the S-meter amplifier Q210, 2SC828Q, for S-meter indication.

3. Squelch Circuit

The voltage variation at the collector of S-meter amplifier Q210, 2SC828Q, is fed to the Schmit circuit Q211 and Q212, 2SC372Y, through the squelch threshold control. When incoming signal disappears, the collector voltage of Q210 and Q212 rises in order to conduct squelch control transistor Q213, 2SC372Y. Q213 is so connected in parallel to the output of audio amplifier Q214 that conduction of Q213 shorts the audio signal pass between Q214 and Q215 to the ground. When signal is received, Q213 stops conducting and the audio signal is fed to Q215 from Q214.

4. Clarifier Circuit

A varactor diode D601, 1S2236 is connected to the VFO tank circuit in order to tune the receiver frequency a few kHz either side of the transmitting frequency. In receive mode, the bias voltage for D601 is fed through the clarifier control VR5, and in transmit mode this voltage is fed from the voltage divider R3 and R4.

5. Output Indicator

A part of the RF output power is fed to the RF rectifier D1, 1S188, through capacitor C1 and the rectified DC voltage is used to read relative power output on the meter.

6. ALC (Automatic Level Control) Circuit

The ALC rectifier diode D504, 1S188, is so biased that it conducts for only higher signal than predetermined level. The audio signal detected by D504 is rectified by the voltage doubler D505 and D506, V06B, and then fed to the transmitter IF stage Q205 and Q206 to control the IF gain in order to prevent distortion due to over drive. $\sqrt{R} SO3 ALC ADJUST$

7. AFP (Automatic Final Protection) Circuit

This circuit is provided to protect the final transistor against over load condition, which may occur if the transmitter is keyed without an antenna or with a high VSWR antenna system.

When the reflected power increases, the diode D503, 1S188, detects the voltage and supplies a control voltage to the gate of controller D402, CW01B, which conducts through AFP threshold control VR502. Thus supply voltage to the transmitter second mixer drops and the mixer gain decreases to protect the following stages.

CW BREAK-IN AND SIDETONE

With the key down, a phase shift oscillator Q901, 2SC372Y, generates 800 Hz sidetone signal and is fed through sidetone level control VR901 to the audio amplifier Q215 for the sidetone monitoring. A part of the 800 Hz from Q901 is amplified by Q902, 2SC372Y, and rectified by D901 and D902, 1S1555. This negative voltage cuts off Q903, 2SK19Y, in turn a relay control transistor Q904, 2SC372Y, conducts to activate the relay RL1 and the signal is transmitted. With the key up, Q904 stops conducting and the relay recovers into receive condition. The relay hold time can be adjusted by VR902.

CRYSTAL CALCULATION FOR CRYSTAL CONTROLLED OPERATION

The crystal holders accept standard HC-25/U type crystals. All crystal frequencies must fall between 5,000 kHz and 5,500 kHz. A trimmer capacitor is connected in series with each crystal to permit proper frequency adjustment within approximately 1 kHz.

The correct crystal frequency of any desired operating frequency may be determined by the following formula:

$$f_x = f_1 - f_0$$

When f_x is the crystal frequency, f_0 is the operating frequency and the constant f_1 is taken from the following table.

BAND (MHz)	LSB	USB	AM/CW
50.0 ~ 50.5	55501.5	55498.5	55499.3
50.5 ~ 51.0	56001.5	55998.5	55999.3
51.0 ~ 51.5	56501.5	56498.5	56499.3
51.5 ~ 52.0	57001.5	56998.5	56999.3
52.0 ~ 52.5	57501.5	57498.5	57499.3
52.5 ~ 53.0	58001.5	57998.5	57999.3
53.0 ~ 53.5	58501.5	58498.5	58499.3
53.5 ~ 54.0	59001.5	58998.5	58999.3

Table 1

For example;

Find the proper crystal for operation at 51.9 MHz USB.

From the table, the constant f₁ is 56998.5 kHz. Therefore, $f_x = 56998.5$ kHz - 51900 kHz = 5098.5 kHz.

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CAUTION

NEVER OPERATE THE TRANSCEIVER IN TRANSMIT MODE WITHOUT A MATCHED ANTENNA OR ADEQUATE DUMMY LOAD.

GENERAL

The transceiver has been carefully aligned and tested at the factory and, with normal usage, should not require other than usual attention given to electronic equipment. Service or replacement of a major component may require subsequent realignment, but under no circumstance should realignment be attempted unless the operation of the transceiver is fully understood and the malfunction has been analized and definitely traced to misalignment. Service work should only be performed by experienced personnel, using the proper test equipment.

EQUIPMENT REQUIRED

- RF Signal Generator with one volt output at an impedance of 50 ohms and a frequency coverage of 5 MHz to 60 MHz.
- (2) Vacuum Tube Voltmeter (VTVM), Hewlett Packard model 401B, or equivalent with a RF-probe good to 60 MHz.
- (3) Dummy Load, 50 ohms non-reactive load rated at 20 watts, Yaesu model YP-150, or equivalent.
- (4) Frequency Counter, Yaesu model YC-355D, or equivalent.
- NOTE : Cores in coil form are fixed by wax. Melt the wax with hot soldering iron to adjust cores.

RECEIVER

1. S-Meter Adjustment

Disconnect the antenna from the antenna terminal. Set the transceiver to receive mode. Set VR202 in the IF AF board to fully clockwise position. Adjust VR204 until the meter shows full scale. Set the VR202 fully counter-clockwise position and adjust VR203 until the meter shows zero reading.

2. Noise Blanker Threshold Level

The operating level of the noise blanker is determined by the threshold control VR201. With the noise blanker OFF position, tune in a signal on any band that registers S9. Note the S-meter changes when the noise blanker is placed in the circuit. When the noise blanker level is adjusted properly by VR201, the meter should indicate a decrease of one of half S-unit. Excessive setting of the threshold control may result in the cross-modulation.



BOTTOM VIEW

3. Squelch Threshold Level

Set the mode switch to SSB mode and disconnect the antenna from the antenna terminal. Set the SQUELCH control on the front panel to 3 position. Adjust VR4 (THRESHOLD) to the point where the noise disappears.

4. Clarifier

Set the clarifier control to OFF position. Tune in a signal and zero beat in the USB mode. Set the clarifier control to zero, 12 o'clock position. Adjust VR6 (0-SET) for zero beat.



TOP VIEW

CAUTION

CONTINUOUS FULL OUTPUT FOR MORE THAN 10 SECONDS MAY RESULT IN DESTRUCTION OF THE FINAL POWER TRANSISTOR.

Connect a 50 ohm dummy load to the antenna terminal. Set the BAND switch to 52 MHz. Adjust L411 - L415, TC406 and TC501 - TC504 for maximum output.

1. AFP (Automatic Final Protection) Circuit

THE FOLLOWING ADJUSTMENT SHOULD BE COMPLETED IN A SHORT TIME TO PROTECT THE FINAL TRANSISTOR.

Tune up the transceiver for full output into the dummy load in the CW mode. Set VR502 in the final amplifier unit fully counterclockwise and disconnect the dummy load from the antenna jack. Carefully observing the power output indication (meter switch at P.O. position), advance the VR502 clockwise until the meter indication abruptly drops to zero. Set the transceiver to receive mode and connect the dummy load to the antenna jack. Then transmit again and check the transmitter works normally.

2. CW Break-in Hold Time

The relay hold time of the CW break-in operation can be adjusted by VR902 located on the CW TONE UNIT for a comfortable operation. Clockwise rotation makes longer hold time.

3. CW Sidetone Level

The sidetone level is adjusted by VR8 for comfortable operating level.

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OPTIONAL UNIT * 100 KHz Marker Oscillator * 6 KHz Crystal Filter for AM (XF90B)



PB-1428 1 st LOCAL OSC UNIT



PB-1414 FIX CHANNEL OSC UNIT



PB-1417 AF-IF UNIT







PB-1427 CW TONE UNIT



PB-1431 REG UNIT

PARTS LIST

MAIN CHASSIS	1 JSO-239
PB-PRINTED CIRCUIT BOARD	2 SG-7615
1360(A~Z) LAMP BOARD	3 SB-0822
$1421(A \sim Z) VR BOARD$	4 QMS-AB4M
	5 FM-146S
Q-TRANSISTOR	6 SG-7814
1 2N3055	7 SG-8050
	8 CN-1463
D D-DIODE	
1 DS-130-ND	F-FUSE
2 V06B	1 2A
R-REISTOR	FH-FUSE HOLDER
CARBON FILM	1 SN-1001
8 ¼W 150KΩ	
CARBON COMPOSITION	PL-PILOT LAMP
6 ½W 10Ω	1,2 15V 0.15A
7 ½W 100Ω	3,4 6V 65mA
2 ½W 150Ω	
1 ½W 10KΩ	PLH-PILOT LAMP HOLDER
3,5 ½W 33 ΚΩ	1,2 BH641-01361B
4 ½W 47KΩ	
VR-POTENTIOMETER	RF MIX UNIT
1,7 VM20A-5KB 5KΩB	PB-PRINTED CIRCUIT BOARD
2 VM13A-5M3121-5KA 5KΩA with PULL SW	1419 $(A \sim Z)$ RF, MIX BOARD
3 VM11A-5M1112-50KB 50KΩB with SW	
5 VM11A-5M1222 50KB 50KQB with SW	Q-FET & TRANSISTOR
7 VM20A-5KB 5KΩB	401,403,404 FET 3SK40M
8 EVH-BOAR15A14 10KΩB	402,405 FET 2SK19Y
4,6 TR11R	406 2SC784R
	407 2SC1216
C-CAPACITOR	
DIPPED MICA	D-DIODE
1 50WV 3PF	401 Si V06B
CERAMIC DISC	402 Thyristor CW01B
$2 \sim 5, 10, 11$ 50WV $0.0047 \mu F$	
7,8 1.4KWV 0.0047µF	R-RESISTOR
MYLAR	CARBON FILM
6 50WV 0.1μF	427, 429, 441 ¹ / ₄ W 56Ω
ELECTROLYTIC	408, 412, 416, 420, 439 ¼W 100Ω
12 25WV 470μF	419,424,442 ¹ / ₄ W 220Ω
9 25WV 3300µF	407 ¹ / ₄ W 330 Ω
	414 ¹ / ₄ W 470Ω
VC-VARIABLE CAPACITOR	428 ¹ / ₄ W 560 Ω
1 C512C	410 , 417 , 421 , 426 ¹ / ₄ W 1KΩ
2 C365A	406 ¹ / ₄ W 1.5KΩ
	415 ¹ / ₄ W 2.2KΩ
RFC-RF CHOKE	423, 425, 436 ¼W 10KΩ
1 2mH	404,435 ½W 22KΩ
	418, 422, 438 ¹ / ₄ W 33 KΩ
PT-TRANSFORMER	401, 402, 403, 405, 409, 411 ¼W 100KΩ
1 52-26	437 ¹ / ₄ W 150KΩ
	1 / 7 7
	413 ¹ / ₄ W 220KΩ
M-METER	CARBON COMPOSITION
M-METER 1 FT620B S/PO	CARBON COMPOSITION 432 ½W 2.2Ω
1 FT620B S/PO	CARBON COMPOSITION 432 ½W 2.2Ω 434 ½W 5.6Ω
1 FT620B S/PO SP-SPEAKER	CARBON COMPOSITION 432 ½W 2.2Ω 434 ½W 5.6Ω 431 ½W 10Ω
1 FT620B S/PO	CARBON COMPOSITION 432 ½W 2.2Ω 434 ½W 5.6Ω
I FT620B S/PO SP-SPEAKER 4Ω3W	CARBON COMPOSITION 432 ½W 2.2Ω 434 ½W 5.6Ω 431 ½W 10Ω 430 ½W 22Ω
I FT620B S/PO SP-SPEAKER 4Ω3W I SA-70 4Ω3W RL-RELAY I	CARBON COMPOSITION 432 ½W 2.2Ω 434 ½W 5.6Ω 431 ½W 10Ω 430 ½W 22Ω C-CAPACITOR
I FT620B S/PO SP-SPEAKER 4Ω3W	CARBON COMPOSITION 432 ½W 2.2Q 434 ½W 5.6Q 431 ½W 10Q 430 ½W 22Q C-CAPACITOR DIPPED MICA
1 FT620B S/PO SP-SPEAKER 4Ω3W 1 SA-70 4Ω3W RL-RELAY 1 AE-3171	CARBON COMPOSITION 432 ½W 2.2Q 434 ½W 5.6Q 431 ½W 10Q 430 ½W 22Q C-CAPACITOR DIPPED MICA 429,437,438,445 50WV 1PF
1 FT620B S/PO SP-SPEAKER 1 1 SA-70 4Ω3W RL-RELAY 1 AE-3171 RLS-RELAY SOCKET 1	CARBON COMPOSITION 432 ½W 2.2Ω 434 ½W 5.6Ω 431 ½W 10Ω 430 ½W 22Ω C-CAPACITOR DIPPED MICA 429,437,438,445 50WV 1PF 447 50WV 10PF
I FT620B S/PO SP-SPEAKER 4Ω3W I SA-70 4Ω3W RL-RELAY AE-3171	CARBON COMPOSITION 432 ½W 2.2Ω 434 ½W 5.6Ω 431 ½W 10Ω 430 ½W 22Ω C-CAPACITOR DIPPED MICA 429,437,438,445 50WV 1PF 447 50WV 10PF 418,421,439 50WV 20PF
1 FT620B S/PO SP-SPEAKER 1 1 SA-70 4Ω3W RL-RELAY 1 AE-3171 RLS-RELAY SOCKET 1 1 AE-3860 1	CARBON COMPOSITION 432 ½W 2.2Ω 434 ½W 5.6Ω 431 ½W 10Ω 430 ½W 22Ω C-CAPACITOR DIPPED MICA 429,437,438,445 50WV 1PF 447 50WV 10PF 418,421,439 50WV 20PF 402,407,410,428,441 50WV 30PF
1 FT620B S/PO SP-SPEAKER 1 1 SA-70 4Ω3W RL-RELAY 1 AE-3171 RLS-RELAY SOCKET 1 1 AE-3860 SW-SWITCH	$\begin{tabular}{ c c c c c } \hline CARBON & COMPOSITION \\ \hline 432 & $\frac{1}{2}W & 2.2\Omega \\ \hline 434 & $\frac{1}{2}W & 5.6\Omega \\ \hline 431 & $\frac{1}{2}W & 10\Omega \\ \hline 430 & $\frac{1}{2}W & 22\Omega \\ \hline \\ \hline $
1 FT620B S/PO SP-SPEAKER 1 1 SA-70 4Ω3W RL-RELAY 1 AE-3171 RLS-RELAY SOCKET 1 1 AE-3860 1	$\begin{tabular}{ c c c c c } \hline CARBON & COMPOSITION \\ \hline 432 & $\frac{1}{2}W & $2,2\Omega$ \\ \hline 434 & $\frac{1}{2}W & $5,6\Omega$ \\ \hline 431 & $\frac{1}{2}W & 10Ω \\ \hline 430 & $\frac{1}{2}W & 22Ω \\ \hline \\ \hline $
1 FT620B S/PO SP-SPEAKER 1 1 SA-70 4Ω3W RL-RELAY 1 AE-3171 RLS-RELAY SOCKET 1 1 AE-3860 SW-SWITCH	$\begin{tabular}{ c c c c c } \hline CARBON & COMPOSITION \\ \hline 432 & $\frac{1}{2}W & 2.2\Omega \\ \hline 434 & $\frac{1}{2}W & 5.6\Omega \\ \hline 431 & $\frac{1}{2}W & 10\Omega \\ \hline 430 & $\frac{1}{2}W & 22\Omega \\ \hline \\ \hline $

412, 422, 434	4 50WV	100PF	287	1⁄4 W	330 \$
460	50WV	200PF	203,291,292	1⁄4 W	4705
	CERAMIC		217,218,220,221	1⁄4 W	560 \$
409,419	50WV	0.5PF	210, 224, 227, 233, 23		1KS
	CERAMIC DISC	C	239, 243, 257, 266, 27		
456~459	50 W V	$0.001 \mu F$	272,273,288		•••••••••••••••••••••••••••••••••••••••
416,423,433	3,446,468, 50WV	0.01µF	209	1⁄4 W	1.5Kg
404~406,40		0.047µF	214,235,246,249,	1/4 W	2.2KS
424,426,431			255,293		
450~453,46			212,213,219,222,22	$\frac{1}{4}$ W	3.3KS
	ELECTROLYTI	С	230,240,242,252,25		0.0113
467	16WV	4.7μF	268,271,274,275,28		
10.		1.17,21	202,264,286,289	1/4 W	4.7KS
VC-VA	RIABLE CAPACITO	 }P	232,253	1/4 W	6.8KG
401	C332A	18PF×3	238,247,248,277,27		0.0K3
402	C365A	18PF×6	259	1/4 W	18KG
402			251,258,280	<u></u> <u>1⁄4</u> W	22KG
TC.TP	IMMER CAPACITO	Þ	201,205,231,282	<u>14 W</u>	27KS
401~406	ECV-1ZW	40P32	262	1/4 W	33KG
401~400	ECV-12W	40P32			
	10700		260,267	<u>14 W</u>	39KG
	JCTOR		245	<u>1⁄4 W</u>	47KS
401		# LR100	208,211,223,226,25	$\frac{1}{4}$ W	100KS
402,403		#LR101,102	263,290		
404,405		#LR103, #104	284	1⁄4 W	470KS
406		#4170	244	1⁄4 W	<u>1M</u> Ω
407	IF (Transmit)	# 4170			
408~410	MIX (")	#LR105	VR-POTENTIC	DMETER	
411~415	6m Amp(")	#LR106,107,108	202,203 SR19	R	470 ΩE
		<u></u>	204 SR19	R	2.2 ΩE
RFC-R	F CHOKE		201 SR19	R	10K ΩE
401	CHOKE COIL	# LR115		······································	
402	CHOKE COIL	#LR116	C-CAPACITOR	2	
		<u>_</u>		PPED MICA	
P&. I-C	ONNECTOR	······	203	50WV	
401		28-6-10-181P(S)	257	50WV	15PH
402,403		8-11-10-181P(S)	238, 258, 261	50WV	
404		Q-4052 (PLUG)	_206,270,274	<u>50WV</u>	
•··-·	5	Q-3056 (JACK)	220	50WV	47 PI
			267	50WV	56 P I
			209,239,268,282	50WV	100 PH
	IF AF UNIT		233	50WV	470PI
	INTED CIRCUIT B	IOARD	262	50WV	620PI
$1417(A \sim Z)$	IF · AF BOARD			CERAMIC	
			212	50WV	<u>0.5P</u>
	ET & TRANSIST			AMIC DISC	
208	IC	TA-7045M	242	50WV	0.001µF
	· · · · · · · · · · · · · · · · · · ·				
215	IC	AN-214	201, 213, 218, 221, 22	25, <u>50WV</u>	0.01µI
215 203,205,206	IC 5,218 FET	AN-214 2SK19GR		25, 50WV	
215	IC 5,218 FET		201, 213, 218, 221, 22		
215 203,205,206	IC 5,218 FET	2SK19GR	201,213,218,221,22 240,241,281	217, 50WV	0.01µH
215 203,205,206 204,211~21	IC 5,218 FET 14,217,219	2SK19GR 2SC372Y	201,213,218,221,22 240,241,281 202,205,208,215~2	217, 50WV 228~230,	0.01µH
215 203,205,206 204,211~21 216 •	IC 5,218 FET 14,217,219	2SK19GR 2SC372Y 2SC710D	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2	217, 50WV 228~230,	0.01µH
215 203,205,206 204,211~21 216 • 201,202,207	IC 5,218 FET 14,217,219	2SK19GR 2SC372Y 2SC710D 2SC784R	201,213,218,221,22 240,241,281 202,205,208,215~2 219,222~224,226,2 232,234,235,237,26	217, 50WV 228~230, 50,263,	0.01µH
215 203,205,206 204,211~21 216 • 201,202,207 209,210	IC 5,218 FET 14,217,219 7	2SK19GR 2SC372Y 2SC710D 2SC784R	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279	217, 50WV 228~230, 50,263, MYLAR	0.01µH 0.047µH
215 203,205,206 204,211~21 216 • 201,202,207 209,210 D-DIOD	IC 5,218 FET 14,217,219 7 DE	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283	217, 50WV 228~230, 50,263, MYLAR 50WV	0.01µH 0.047µH 0.047µH
215 203,205,206 204,211~21 216 • 201,202,207 209,210 D-DIOD 205~209,21	IC 5,218 FET 14,217,219 7 DE 11,214 Ge	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV	0.01µH 0.047µH 0.01µH 0.01µH
215 203,205,206 204,211~21 216 • 201,202,207 209,210 D-DIOD 205~209,21 204,212,213	IC 5,218 FET 14,217,219 7 DE 11,214 Ge 3 Ge	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV	0.01µH 0.047µH 0.01µH 0.01µH 0.047µH 0.033µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOC 205~209,21 204,212,213 201,202,210	IC 6,218 FET 14,217,219 7 DE 11,214 Ge 3 Ge 0 Si	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV	0.01µH 0.047µH 0.01µH 0.01µH 0.033µH 0.1µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOD 205~209,21 204,212,213 201,202,210 215	IC 5,218 FET 14,217,219 7 DE 11,214 Ge 3 Ge 0 Si Si	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV	0.01µH 0.047µH 0.01µH 0.01µH 0.047µH 0.033µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOC 205~209,21 204,212,213 201,202,210	IC 6,218 FET 14,217,219 7 DE 11,214 Ge 3 Ge 0 Si	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV 7ANTALUM	0.01µH 0.047µH 0.047µH 0.01µH 0.047µH 0.033µH 0.1µH 0.22µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOD 205~209,21 204,212,213 201,202,210 215 203	IC 6,218 FET 14,217,219 7 7 7 DE 11,214 3 Ge 0 Si Si Si Zener 2	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV 7ANTALUM 16WV	0.01µH 0.047µH 0.01µH 0.01µH 0.033µH 0.1µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOC 205~209,21 204,212,213 201,202,210 215 203 X-CRY	IC 5,218 FET 14,217,219 7 DE 11,214 Ge 3 Ge 0 Si Si Zener 'STAL	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV 50WV 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOD 205~209,21 204,212,213 201,202,210 215 203	IC 6,218 FET 14,217,219 7 7 7 DE 11,214 3 Ge 0 Si Si Si Zener 2	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215~2 219, 222~224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 243 EL 246	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV 50WV 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOE 205~209,21 204,212,213 201,202,210 215 203 X-CRY 201	IC 6,218 FET 14,217,219	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV 50WV 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 1µH 4.7µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOE 205~209,21 204,212,213 201,202,210 215 203 X-CRY 201	IC 5,218 FET 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 6 8 Ge 9 Si 2 Si 2 Ener YSTAL FILTER	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215~2 219, 222~224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 243 EL 246	217, 50WV 228~230, 50,263, MYLAR 50WV	0.01µH 0.047µH 0.047µH 0.01µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 1µH 4.7µH
215 203,205,206 204,211~21 216 · 201,202,207 209,210 D-DIOE 205~209,21 204,212,213 201,202,210 215 203 X-CRY 201	IC 5,218 FET 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 6 8 Ge 9 Si 2 Si 2 Ener YSTAL FILTER	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV 50WV 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 1µH 4.7µH
215 203, 205, 206 204, 211 ~ 21 216 · 201, 202, 207 209, 210 D-DIOE 205~209, 21 204, 212, 213 201, 202, 210 215 203 X-CRY 201	IC 5,218 FET 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 6 8 Ge 90 Si Si 2 Stat 2 FILTER AM AM 900	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215~2 219, 222~224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269	217, 50WV 228~230, 50,263, MYLAR 50WV	0.01µH 0.047µH 0.047µH 0.01µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 1µH 4.7µH
215 203,205,206 204,211~21 216 201,202,207 209,210 D-DIOL 205~209,21 204,212,213 201,202,210 215 203 X-CRY 201 XF-CR	IC 5,218 FET 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 6 8 Ge 90 Si Si 2 Stat 2 FILTER AM AM 900	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 243 EL 243 EL 246 276 244, 245, 254, 269 248, 253	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV 50WV CANTALUM 16WV ECTROYTIC 16WV 16WV 16WV 16WV	0.01µH 0.047µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 1µH 4.7µH 10µH 4.7µH
215 203,205,206 204,211~21 216 201,202,207 209,210 D-DIOE 205~209,21 204,212,213 201,202,210 215 203 X-CRY 201 201 202	IC 5,218 FET 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 8 8 Ge 9 8 9 900 SSB 900	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251 256	217, 50WV 228~230, 50,263, MYLAR 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 1µH 4.7µH 10µH 4.7µH 10µH 47µH
215 203,205,206 204,211~21 216 201,202,207 209,210 D-DIOE 205~209,21 204,212,213 201,202,210 215 203 X-CRY 201 201 202	IC 5,218 FET 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz 00KHz(OPTION) 00KHz	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV 50WV 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 1µH 4.7µH 10µH 47µH
215 203, 205, 206 204, 211 ~ 21 216 · 201, 202, 207 209, 210 D-DIOL 205~209, 21 204, 212, 213 201, 202, 210 215 203 X-CRY 201 202 R-RES	IC 5,218 FET 14,217,219 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 6 8 Ge 9 5 7 7 7 7 7 8 7 9 8 90 8 90 8 90 8 90 8 90 8 90 8 90 8 8 9	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz 00KHz(OPTION) 00KHz	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251 256 252	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV 50WV CANTALUM 16WV 16WV 16WV 16WV 16WV 16WV 16WV 16WV 16WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 1µH 4.7µH 10µH 4.7µH 10µH 47µH
215 203, 205, 206 204, 211 ~ 21 216 · 201, 202, 207 209, 210 D-DIOL 205~209, 21 204, 212, 213 201, 202, 210 215 203 X-CRY 201 202 R-RES 250	IC 5,218 FET 14,217,219 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 6 8 Ge 9 5 7 7 7 7 7 5 8 Ge 9 10 8 10 8 900 8 900 8 8 9 10 8 9 8 9 8	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz 9000.7KHz 00KHz(OPTION) 00KHz	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251 256 252 TC-TRIMMER	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV CANTALUM 16WV 16WV 16WV 16WV 16WV 16WV 16WV 16WV 16WV 16WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 10µH 4.7µH 10µH 47µH 100µH 220µH
215 203, 205, 206 204, 211 ~ 21 216 · 201, 202, 207 209, 210 D-DIOL 205~209, 21 204, 212, 213 201, 202, 210 215 203 X-CRY 201 202 R-RES 250 261	IC 5,218 FET 14,217,219 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 8 7 9 7 9 7 9 7 9 7 9 8 9 8 9 8 9 8 9 8 9 8 9 8 9 8 9 </td <td>2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz 00KHz(OPTION) 00KHz 4 22Ω 82Ω</td> <td>201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251 256 252 TC-TRIMMER 201 ECV-</td> <td>217, 50WV 228~230, 50,263, MYLAR 50WV</td> <td>0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 10µH 4.7µH 10µH 4.7µH 10µH 47µH 100µH 220µH</td>	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz 00KHz(OPTION) 00KHz 4 22Ω 82Ω	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251 256 252 TC-TRIMMER 201 ECV-	217, 50WV 228~230, 50,263, MYLAR 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 10µH 4.7µH 10µH 4.7µH 10µH 47µH 100µH 220µH
215 203, 205, 206 204, 211 ~ 21 216 · 201, 202, 207 209, 210 D-DIOL 205 ~ 209, 21 204, 212, 213 201, 202, 210 215 203 X-CRY 201 XF-CR 201 202 R-RES 250 261 204, 207, 225	IC 5,218 FET 14,217,219 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 8 7 8 7 8 7 8 7 8 8 900 8 900 8 900 8 900 8 8 900 8 8 900 8 8 900	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz 9000.7KHz 00KHz(OPTION) 00KHz	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251 256 252 TC-TRIMMER 201 ECV	217, 50WV 228~230, 50,263, MYLAR 50WV 50WV 50WV 50WV 50WV CANTALUM 16WV 16WV 16WV 16WV 16WV 16WV 16WV 16WV 16WV 16WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 10µH 4.7µH 10µH 47µH 100µH 220µH
215 203, 205, 206 204, 211 ~ 21 216 · 201, 202, 207 209, 210 D-DIOE 205~209, 21 204, 212, 213 201, 202, 210 215 203 X-CRY 201 XF-CR 201 202 R-RES 250 261 204, 207, 225 234, 237, 241	IC 5,218 FET 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz 9000.7KHz 00KHz(OPTION) 00KHz 4 22Ω 82Ω 100Ω	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251 256 252 TC-TRIMMER 201 ECV- 202 ECV	217, 50WV 228~230, 50,263, MYLAR 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 10µH 4.7µH 10µH 4.7µH 10µH 47µH 100µH 220µH
215 203, 205, 206 204, 211 ~ 21 216 · 201, 202, 207 209, 210 D-DIOL 205~209, 21 204, 212, 213 201, 202, 210 215 203 X-CRY 201 XF-CR 201 202 R-RES 250 261 204, 207, 225	IC 5,218 FET 14,217,219 14,217,219 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 7 8 7 8 7 8 7 8 7 8 8 900 8 900 8 900 8 900 8 8 900 8 8 900 8 8 900	2SK19GR 2SC372Y 2SC710D 2SC784R 2SC-828R 1S188FM 1S1007 1S1555 V06B WZ110 9000.7KHz 00KHz(OPTION) 00KHz 4 22Ω 82Ω	201, 213, 218, 221, 22 240, 241, 281 202, 205, 208, 215 ~ 2 219, 222 ~ 224, 226, 2 232, 234, 235, 237, 26 265, 266, 273, 279 211, 271, 283 210 247, 280, 284 249, 250, 275 255, 264 7 243 EL 246 276 244, 245, 254, 269 248, 253 251 256 252 TC-TRIMMER 201 ECV-	217, 50WV 228~230, 50,263, MYLAR 50WV	0.01µH 0.047µH 0.047µH 0.047µH 0.033µH 0.1µH 0.22µH 4.7µH 10µH 4.7µH 10µH 4.7µH 10µH 47µH 100µH 220µH

205	OSC.	9MHz #4170	P&J-P	IN CONNECT	OR	
			301	128-15-10-1	81 $P(S)$	
RFC-RF	CHOKE					
207		10µH				
202~206,208	· · · · · · · · · · · · · · · · · · ·	250µH		LOCAL OS		
201,209		1mH		INTED CIRCU		
			1428	LOCAL OS	SC BOARD	
P& I-PIN	ONNECTOR					
	128-8-10-181 P(S)			NSISTOR	· · · · · · · · · · · · · · · · · · ·	
				NSISTUR		
202,203	128-15-10-181 P(S)		701			C373
			702,703		28	C784R
	MIC AMP UNIT		X-CPV	STAL	· · · · · · · · · · · · · · · · · · ·	
	NTED CIRCUIT BOA			HC-25/U	64.5MHz	
			701	HC-25/U		
$1420(A \sim Z)$	MIC AMP BOARD		702	HC-25/U	65.0MHz	
			703	HC-25/U	65.5MHz	
Q- Q-TRAN	ISISTOR		704	HC-25/U	66.0MHz	
		00007037	705	HC-25/U	66.5MHz	
301~303		2SC372Y				
304,305		2SC710D	706	HC-25/U		
		-	707	HC-25/U	67.5MHz	(")
D-DIODE	E		708	HC-25/U	68.0MHz	
		Ge 1S1007				<u>`</u>
301~304					/ mm 100	
305		Si 1S1555		YSTAL SOCI	KET	
			701~708	S2-101P		
X-CRYS						
		0001 5177		ISTOD		
301	HC-18/U	9001.5kHz	R-RES	ISTOR		
302	HC-18/U	8998.5kHz		CARBON	FILM	
			706,712	1	W W	100Ω
R-RESIS	STOP		713		W W	220Ω
	CARBON FILM		701,711		¥W	470 Ω
311,317,321	1∕4 W	100 Ω	705		₩¥W	680 Ω
322~325	1/4 W	220 Ω	708		W	1K Ω
310,313		<u>470</u> Ω	709		4 W	3.3KΩ
316,320	1⁄4 W	560 Ω	702,710		¼W	<u>10K</u> Ω
303,305,309	1⁄4 W	1K Ω	707		¼W	18K Ω
306,326	1/4 W	3.3KΩ	703,704		W W	22K Ω
			103,104		4 11	2211.02
302	1⁄4 W	3.9K Ω				
304,308,314,	318 ¼W	4.7K Ω	C-CAP	ACITOR		
307	1⁄4 W	22K Ω		DIPPED	MICA	
301,315,319		33K Ω	701~709,71		50WV	10PF
					-	
312	1⁄4 W	100K Ω	721		50WV	15PF
			712,713	5	50WV	20PF
VR-POT	ENTIOMETER		722		50WV	51PF
301,302		000 OD		CERAMIC		0111
301,302	SRIPR	220ΩB				
			716		50WV	$0.001 \mu F$
C-CAPA	CITOR		710,711,715	5,717,720	50WV	0.01µF
	DIPPED MICA		718,719		50WV	0.047µF
220		1400	110,115			0.047/21
332	50WV	10PF				
314,319	50WV	15PF	TC-TR	IMMER CAP	ACITOR	
315,320	50WV	20PF	701~716	ECV-1ZW		20P51
328	50 W V	51PF	1			
301,302	50WV			JCTOR	-	
301,302		240PF			~	
	CERAMIC DISC		701	LOCAL OS		# 2201
318,323	50WV	0.001µF	702	LOCAL OS	SC	# 4599
324, 329~332		0.01µF	703	OSC. OUT		#4102
317,322,325	50WV	-		000.001		T 1102
317,322,323		0.047µF		-		
	MYLAR		RFC-R	F CHOKE		
307	50WV	0.0033µF	701			10µH
	ELECTROLYTIC	······································				······································
303,305,306,		1	C-DAN	D SWITCH		
		<u>1µF</u>				
304,309,313	16WV	10µF	701	2-2-8		
308,310	16WV	$47 \mu F$	2			
			P&J-P	IN CONNECT	OR	
TC-TP			1 701	128-7-10-19		
	MMER CAPACITOR	00500	701	128-7-10-18	1 1(0)	
301,302	ECV-1ZW	20P32	701	128-7-10-18	<u>,1 (5)</u>	
		20P32 50P32	701	128-7-10-18	,1 (0)	
301,302	ECV-1ZW		701	,		
301,302 303	ECV-1ZW ECV-1ZW		~	VFO L	JNIT	
301,302 303	ECV-1ZW ECV-1ZW CTOR	50P32	PB-PR	VFO U	JNIT UIT BOARI	D
301, 302 303 L-INDU 301, 302	ECV-1ZW ECV-1ZW CTOR OSC.	50P32 9MHz #4170	PB-PR	VFO L	JNIT UIT BOARI	D
301,302 303	ECV-1ZW ECV-1ZW CTOR	50P32	PB-PR	VFO U	JNIT UIT BOARI	D
301, 302 303 L-INDU 301, 302	ECV-1ZW ECV-1ZW CTOR OSC.	50P32 9MHz #4170	PB-PR 1416(A~Z)	VFO U RINTED CIRC VFO BOAI	UNIT UIT BOARI RD	D
301,302 303 L-INDU(301,302 303	ECV-1ZW ECV-1ZW CTOR OSC. BM.	50P32 9MHz #4170	PB-PR 1416(A~Z) Q-FET	VFO U RINTED CIRC VFO BOAI	UNIT UIT BOARI RD	
301,302 303 L-INDU 301,302 303 RFC-RF	ECV-1ZW ECV-1ZW CTOR OSC.	50P32 9MHz #4170 9MHz #4170	PB-PR 1416(A~Z) Q-FET 603	VFO U RINTED CIRC VFO BOAI	UNIT UIT BOARI RD	2SK19GY
301,302 303 L-INDU 301,302 303 RFC-RF 301	ECV-1ZW ECV-1ZW CTOR OSC. BM.	50P32 9MHz #4170	PB-PR 1416(A~Z) Q-FET	VFO U RINTED CIRC VFO BOAI	UNIT UIT BOARI RD	
301,302 303 L-INDU 301,302 303 RFC-RF	ECV-1ZW ECV-1ZW CTOR OSC. BM.	50P32 9MHz #4170 9MHz #4170	PB-PR 1416(A~Z) Q-FET 603	VFO U RINTED CIRC VFO BOAI	UNIT UIT BOARI RD	2SK19GY
301,302 303 L-INDU 301,302 303 RFC-RF 301	ECV-1ZW ECV-1ZW CTOR OSC. BM.	50P32 9MHz #4170 9MHz #4170 250µH	PB-PR 1416(A~Z) Q-FET 603	VFO URINTED CIRCO VFO BOAT & TRANSIS FET	UNIT UIT BOARI RD	2SK19GY

601	Varactor	1S2236		CERAMIC DISC	
			807,810,811		0.01µF
R-RESISTOR CARBON FILM		TC-TP	IMMER CAPACITOR		
609,611,61		100 Ω		ECV-1ZW	40P32
613	1/4 W	220 Ω			
610 615	<u>1/4</u> W	<u>1KΩ</u>		JCTOR	
615	<u>14 W</u> 14 W	1.5KΩ 2.2KΩ	801,802		2.2µH
603	<u>14 W</u>	<u>3.3KΩ</u>	S-SWI	ТСН	
601	1⁄4 W	10K Ω		5FS-10U-388-1LK	······································
604,608	1⁄4 W	1 8Κ Ω			
607	1/4 W	<u>22KΩ</u>		IN CONNECTOR	
605 612	1/4 W 1/4 W	33KΩ 100KΩ	801,802	128-8-10-181 P(S)	
C-CAF	PACITOR			BOOSTER UNIT	·
610	DIPPED MICA 50WV	6PF		BOOSTER BOARD	,
614	50WV	15PF			
603	50WV	30PF	Q-TRA	NSISTOR	
606	50WV	68PF	501	2SC1306	
616	50WV	100PF	502	2SC1307	
604 607	50WV 50WV	240PF 470PF			
007	CERAMIC DISC	4/0PF	D-DIOC 503,504	Ge	1S188FM
605,608,60	9,611, 50WV	0.01µF	501,502	Varistor	
612,615,61			505,506	Si	V06B
	CERAMIC T.C.				
613	500WV	5PF UJ	R-RES		
601	500WV	10PF UJ		CARBON COMPOSITION	
602	500WV	20PF NPO	507 503,508	<u>1/2 W</u> 1/2 W	<u>56Ω</u> 470Ω
TC-TF	RIMMER CAPACITOR		512	2 W	100KΩ
601	KC30PM	······································	513	1/2 W	1 Μ Ω
	UCTOR			TENTIOMETER	
601	OSC. COIL RFC	# LR112	501	SR19R	470ΩB
602	RFC	250µH	502,503	SR19R	10ΚΩΒ
			C-CAP	ACITOR	
·	FIX UNIT			DIPPED MICA	
	RINTED CIRCUIT BOAR		522	50WV	<u>2PF</u>
) CHANNEL SWITCH) FIX OSC BOARD	BOARD	523 518,521	50WV 50WV	<u>5PF</u> 24PF
1410(M Z			508	50WV	<u>24FF</u>
Q-TRA	ANSISTOR		519,520	50WV	62PF
801,802	2SC372Y		514,515	50WV	82PF
				CERAMIC DISC	
	(STAL (OPTION) HC-25/U 5000kHz	~5500kHz	503,504,506	5,507, 50WV	$0.001 \mu F$
801-804	HC-23/0 3000kH2	JJJUKHZ	510 - 513 501 516 525	5,526,528 50WV	0.01µF
XS-CF	RYSTAL SOCKET		517,524,530		0.047µF
801~804	S14-2P			MYLAR	
			527	50WV	0.1µF
R-RES	SISTOR		500 505 500	ELECTROLYTIC	
808	CARBON FILM	100 Ω	502,505,529 509	9 <u>16WV</u> 16WV	22µF
808	<u></u>	<u>100 Ω</u> 220 Ω	503	10 W V	100µF
803	1⁄4 W	<u>1KΩ</u>	TC-TR	IMMER CAPACITOR	
801	1⁄4 W	5.6KΩ	501,502	ECV-1ZW	50P32
805	<u>14 W</u>	6.8KΩ	503,504	CV08S600	
806	1/4 W	15KΩ	1 181051		· · · · · · · · · · · · · · · · · · ·
802	CARBON COMPOSITION	22KΩ J	501	DRIVER COIL	# LR109
810	¹ / ₂ W	<u>82</u> Ω	502	FINAL COIL	$\frac{\pm LR109}{\pm LR110}$
			503~505	LOW PASS COIL	# LR111
C-CAP	PACITOR				
	DIPPED MICA			RF CHOKE	
801~804	50WV 50WV	<u>10PF</u>	501,502,504	1	# LR115
808 809	50WV	<u>30PF</u> 50PF	503,505 506,507		# LR117
805,806			500,501	· · · · · · · · · · · · · · · · · · ·	250µH
812,813	50WV	400PF	RL-RE	LAY	
	50WV	800PF	501		
814	30 10 1	<u>800FF</u>	501	AL1323	

	ONINECTOR		TO TOWAR		·
501	ONNECTOR PIN 128-11-10-181 PC	(C)		R CAPACITOR	E 0D20
			1001	ECV-1ZW	50P32
503 502	PIN 128-3-10-181 P(SQ4052 (PLUG)	3)		CTOP	
502			L-INDU		# I D110
	SQ3056 (JACK)			9MHz TRAP COIL 14MHz TRAP COIL	# LR113
			1001	14MHz TRAP COIL	# LR114
	CW TONE UNIT		BEC-DE	CHOKE	
DR-DD	NTED CIRCUIT BOAR		1001	CHUKE	22µH
	SIDE TONE BOARD	J	1001		<i>22µ</i> H
$1427(A \sim L)$	SIDE TONE BOARD				
0 - ET					
	& TRANSISTOR	0.0.1/1.0.1/		REG UNIT	
903	FEI	2SK19Y		NTED CIRCUIT BOARD	ر
901,902		2SC372Y	$1431(A \sim Z)$	REG BOARD	
904		2SC735Y			
				ISISTOR	0 F
D-DIOD		101555	101,102	2SD31	
901,902	Si	1S1555	103,104	2SC37	2 Y
903	Zener	WZ 090			
			D-DIOD		
R-RES			101	Silicon Bridge KBL-0	
	CARBON FILM		104	Zener WZ-06	
905	1⁄4 W	220 Ω	102	Zener WZ-09	
916	1⁄4 W	330 Ω	103	Zener WZ-11	10
915	1⁄4 W	680 Ω			
906,910	1⁄4 W	1K Ω	R-RESI		
907	1⁄4 W	2.2K Ω		CARBON FILM	
909,911	1⁄4 W	3.3K Ω	105	1⁄4 W	330 Ω
901~903	1⁄4 W	4.7KΩ	104	1∕4 W	390 Ω
917	1⁄4 W	15K Ω	102	1⁄4 W	470 Ω
908	1⁄4 W	27K Ω	106	1⁄4 W	560 Ω
904	1/4 W	33K Ω	101,103,109	1/4 W	1K Ω
912	1/4 W	470ΚΩ	107.108	1/4 W	3.3KΩ
	CARBON COMPOSITION				
913	½W	3.3MΩ	VR-POT	ENTIOMETER	
914	1/2 W	5.6MΩ	101,102		1ΚΩΒ
	THERMISTOR	0101110			
918	SDT-250		C-CAPA	CITOR	
310	501-200			CERAMIC DISC	
VP-PO	TENTIOMETER		104	50WV	0.047µF
	EVL-S3AA00B26	2M ΩB	104	ELECTROLYTIC	0.047#1
502	EVE-SSAA00B20	2141 32D	103	16WV	220µF
C-CAP	ACITOR		101,102	25WV	1000µF
C-CAP	MYLAR		101,102	20111	1000/21
912	50WV	0.001µF		DKE COIL	
905,906,910		$0.01 \mu F$	101	2.5A	2.4mH
901-903	50WV		101	2.3A	2.400
911	50WV	0.02µF		NCONNECTOR	
911		0.2µF		N CONNECTOR	·
907	ELECTROLYTIC	0.0.5	101	128-15-10-181 P(S)	
	25WV	2.2µF			
909,913	16WV	10µF			() · · · ·
908	16WV	33µF		ARKER UNIT (OPTION	
				NTED CIRCUIT BOARD	
	IN CONNECTOR		1424	MARKER BOARD	I
901	128-5-10-181 P(S)		0.10.0	TRANSISTOR	
4_4 AVA.					
			1203	IC SN7490N	
00.00			1201,1202	2SC372Y	
	INTED CIRCUIT BOAR	0			
$1423(A \sim Z)$	TRAP BOARD		D-DIOD	A THE CONTRACTOR OF A DESCRIPTION OF A DESCRIPANTE A DESCRIPANTE A DESCRIPANTE A DESCRIPTION OF A DESCRIPTIO	
			1201	Zener 1S330	
D-DIOD					
1001	Gi 1S1881	- M	X-CRYS		
			1201	HC-6/U	1MHz
R-RES					
1001	CARBON FILM 1/4 W	1.5K Ω	R-RESI		
				CARBON FILM	
C-CAP	ACITOR		1205	1/4	220 Ω
	DIPPED MICA		1203	1/4	1K Ω
1004	50WV	150PF	1202	1/4	10K Ω
1003	50WV	240PF	1201	1/4	22K Ω
1001,1002	50WV	680PF	1204	1/4	470K Ω
	CERAMIC DISC				
1005	50WV	0.047µF	C-CAP	ACITOR	
· · · · · · · · · · · · · · · · · · ·				DIPPED MICA	

1205	50WV	5PF	
1206	50WV	39PF	
1201,1202	50WV	1500PF	
	CERAMIC DISC		
1203,1204	50W V	$0.01 \mu F$	
TC-TR	IMMER CAPACITOR		
1201	ECV-1ZW	50P32	
P&J-P	IN CONNECTOR		
1201	128-3-10-181 P(S)		

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FT-620B 6-METER TRANSCEIVER

INSTALLATION OF MARKER UNIT

- (1) Locate space for the marker unit on the chassis. Refer to the top view on Page 25 of the instruction manual.
- (2) Install the unit as illustrated in Fig. 2.
- (3) The marker frequency has been calibrated prior to shipment at the factory. The frequency can be recalibrated, if necessary, by adjusting TC1201.



Fig. 1.

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NAI LATCHES FOR FT-620B COVER. NAI LATCH H322-2-1 Yaesu # S3000001 NAI LATCH H322-2-3-1 Yaesu# S3000005

One of these is the pin and the other is the circular insert. Yaesu parts 714-827-7600

Replacement cover latch for early Yaesu transceivers FT-221, FT-225, FT-625, FT-620B

Fox Tango International http://www.foxtango.org Carol L. Maher W4CLM

REDUCING TVI CAUSED BY FT-101 RX RADIATION

If you happen to be located in an area where reception of TV Channel 4 is marginal and weak, you may notice a series of fixed diagonal lines on your screen when the FT-101 is operating on 10 meters or receiving 11. The interference is not affected by changing to transmit or modulation. It apparently is caused by radiation from the crystal oscillator stage since pulling the crystal will stop the radiation. Fortunately the problem is worse on 11 meters than on 10; the following suggestion from Yaesu should reduce the radiation. [A better and higher TV antenna and the use of shielded downlead: RG-59/U,will also help. NAML.]

- * Remove the bottom cover and locate RL-2 (the Antenna relay) and run one white wire between J-16 (the RCV Ant jack) and RL-2 as shown in Fig 2. To the same point, add one end of a 0.4microhenry choke and one end of a 100pF capacitor and solder into place.
- * Now dress the free end of the capacitor to the chassis ground tab adjacent to the relay socket. Connect one end of a second 100pF capacitor from the rear lug of the RF [Lamp] Fuse holder, and run its free end to the same ground tab and solder both leads to the tab.
- * Dress the free end of the RF Choke to the rear lug of the RF Fuse holder and solder

Diagrams are provided for your assistance.

"SMIRK" RECOMMENDS 3N201 FOR FT-620B

Edition #17 of the Six Meter International Radio Klub contains the following for the '620:

For better gain and signal/noise ratio, replace the 3SK40M in the front end with a 3N201B dual-gate MOSFET. It is the only one in a socket and is designated as Q401....For more gain and less internal noise replace the Q403 in the RX Mixer stage with a 3N201 or a 3N211...Order Item 6A2 from Fox-Tango...\$3 airmail postpaid.

Well, if it improves 6-meter reception, it should do the same for lower-frequency signals. There have been several reports indicating that the 3N201 substitution helps in other rigs than Yaesu--pass the word. No "magic"! Just a better unit, at a fair price.

FLEETING THOUGHTS

What's common to both Yaesu and Kenwood rigs? asks a member. The letter "T", he says, answering his own question. So what? Well, why not add a letter "S" to the "FT" Club designation? It would then look like \underline{FTS} . Club. Or maybe this would make it clearer: \underline{FTS} and \underline{FTS} . Then it could apply to $\underline{both}(i)$

Sorry gentlemen, there are only 24 hours in a day! But would anyone else like to get into the act for the FTS part? It could be a golden opportunity. NAML



THE INTERNATIONAL FOX TANGO CLUB MILTON LOWENS WA2AOO/N4ML 248 LAKE DORA DRIVE W. PALM BEACH, FLORIDA 33411	BULK RATE U. S. POSTAGE P A I D W. Palm Beach, FL PERMIT No. 285	In this issue: (Year 8, Number 1) January, 1979
10		Editorial: New Year's GreetingsBasic ideas for improving the FT-101 ReceiverFT-7 Modifi- cationsThe 1800Hz SSBthe why and wherefore, including some reports on its operationFor SaleMore reactions to, and modifications for, the FT-901DMCustoms relief for Canadian hams (we hope)An "insurance" modification for the FT-901 series
		Plus more in the Supplement, including a new Price List for Green Sheet No. 6.
Dated PRINTED MATTER - <u>Please do</u> Printed in the U. S. A.	not Delay!	In case your neighbor wonders why he did not re- ceive this issue, remind him that all subscrip- tions expire Dec. 31. Basic dues are now \$6/ur. FT NET MEETS SATURDAYS, 1700 UTC, 14,325 ± 5KHz

FT-620B ALIGNMENT NOTES

by Bruce Dehn WB70TQ via Ken Thompson K7DNF and the Arizona 6-meter Association

The following instructions to get your FT-620B to perform as it should were supplied as indicated above. To put it mildly, the results on the sets of W7LNX and K7RKL were phenominal [they say]!

If available, put a wattmeter in the line to your load (dummy or antenna) while checking the transmitter.

1. Replace Q401 and Q403 on the RF-MIX board with 3N211 (preferred) or Sylvania ECG222 MOSFET's.

2. Replace C416 (.01) off Q402 with a 10 pF capacitor.

3. Replace C423 (.01) off Q403 with a 10 pF capacitora.

4. Adjust L401, L402, and L403 for peak incoming signal.

5. Adjust TC401, TC402 (near L402 and L403) for peak.

6. Adjust coil L406 for peak.

7. On MIC-AMP board behind mike gain control, turn L301 clockwise until the RX cuts off; then back it until RX just comes on again.

8. Adjust L407 (RF-MIX Board) for peak.

9. Using a mostly plastic screwdriver (such as GC-8276) adjust the following for peak in sequence given: TC405, TC404, TC403

10. In CW position, adjust L411, L413, L412, L414, and L415 for peak output. Do NOT held the keu down for more than 5 seconds at a time.

11. Peak TC406 and L407.

12. Remove shield at left (over TX secion).

13. Peak TC501 and TC502.

14. Repeat steps 9 through 13. Replace shield.

15. Adjust S-meter and noise blanker as per Manual.

16. Remove bottom cover and $\mbox{ adjust }\mbox{ L303 }\mbox{ for maximum noise.}$

17. Adjust VR301 on MIC-AMP board if your signal has any carrier.

18. Adjust for automatic shutdown as per page 26 of the Manual.

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